SUPERCONDUCTIVITY OF SINGLE-CRYSTAL NbGe₂*

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Summary

Small single crystals of NbGe₂ were grown by the hydrogen reduction of potassium-containing oxides. Measurements of electrical resistivity and superconductivity are given.

Matthews et al. [1] were the first to show that the A15 compound Nb₃Ge was a high transition temperature superconductor. Subsequent to the work of Gavaler [2] and later Testardi et al. [3] which pushed the Tc of Nb₃Ge to 23 K, Ghosh and Douglas [4] reported superconductivity to 16 K in sputtered films containing Ge and NbGe₂. It appeared that the Ge-rich portion of the Nb-Ge phase diagram might also be interesting from the standpoint of superconductivity, especially since Hardy and Hulm [5] found the C40 compound NbGe₂ to be normal to 1.2 K. The sputtering target used in ref. 4 had Tc = 1.85 K.

The work described here is based on the observation that KNbO₃ could be reduced to Nb metal in H₂ at relatively low temperatures. This suggested the possible production at relatively low temperature of Nb₃Ge by hydrogen reduction of KNbO₃ and K₂GeO₃ mixtures with a Nb:Ge ratio of 3:1. These mixtures were made both by ball milling the crushed oxides and by reaction of K₂CO₃ with a Nb₂O₅-GeO₂ mixture.

Hydrogen reduction was carried out overnight at temperatures in the range 800 - 1100 °C with little variation in the result. The mass that resulted from this reduction was interspersed with small columnar metallic crystals (typically 0.5 mm × 0.05 mm × 0.05 mm). A measurement of superconductivity on the entire product gave an incomplete transition with Tc onset of 2.0 K.

X-ray analysis of these crystals showed them to be NbGe₂ with lattice parameters a₀ = 4.965 Å, c₀ = 6.783 Å. A quantity of these crystals was isolated, crushed and found to have a Tc onset of 2.1 K and width 0.4 K. It

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is likely, therefore, that the $T_c$ seen in the bulk reduction mass is due to NbGe$_2$. A four-probe electrical resistivity measurement on one of these crystals (Fig. 1) gave $T_c = 2.23 \pm 0.03$ K. The resistance ratio to 4.2 K for this crystal is 100, the room temperature resistivity is $60 \pm 15 \mu\Omega$ cm. An X-ray rotation photograph of one of the crystals showed that its growth axis was $(11\bar{2}0)$.

This result was compared with arc-melted samples at nominal compositions NbGe$_2$ and NbGe$_5$, annealed at 950 °C for one week. The NbGe$_2$ sample had $T_c = 2.09 \pm 0.02$ K and for the NbGe$_5$ sample $T_c = 2.16 \pm 0.01$ K. This last sample reacted somewhat with its protective Ta wrapper, possibly influencing the $T_c$. Nothing in the a.c. susceptibility was observed at higher temperature in either of these samples.

By varying the ratio of Nb:Ge in the initial mixture of oxides we were unable to produce material with a higher transition temperature. The actual mechanism for the growth of the NbGe$_2$ crystals is not clear. The possibilities include vapor growth and growth from KOH flux. It would be interesting to investigate this last possibility, but the container problem for molten KOH under these conditions is severe.

It is interesting that the hydrogen reduction of these oxides proceeds so readily, apparently due to the presence of potassium. This reduction technique might prove useful in the low temperature synthesis of a number of other intermetallics.

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References